

80V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

BV _{DSS}	Rds(on) Max	Ι _D Tc = +25°C		
90)/	3.9mΩ @ V _{GS} = 10V	105A		
80V	6mΩ @ V _{GS} = 6V	87A		

Description and Applications

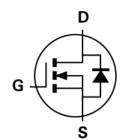
This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Switching
- Synchronous rectification
- **DC-DC** converters

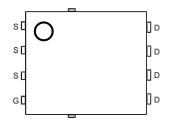


Top View

Bottom View



Internal Schematic



Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMTH8003SPSW-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. Notes:

Pin 1

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable • and Robust End Application
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)

Product Summary



Marking Information



) | | = Manufacturer's Marking TH8003SW = Product Type Marking Code $\overline{YY}WW = Date Code Marking$ YY= Last Two Digits of Year (ex: 24 = 2024)WW= Week Code (01 to 53)

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	80	V	
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 5)	Tc = +25°C Tc = +100°C	lo	105 75	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	420	A
Continuous Body Diode Forward Current (Note 5) T _C = +25°C		ls	105	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)	lsм	420	A	
Avalanche Current, L = 3mH (Note 6)	las	15.8	A	
Avalanche Energy, L = 3mH (Note 6)	Eas	375.4	mJ	
Avalanche Current, L = 0.1mH	las	65	A	
Avalanche Energy, L = 0.1mH	Eas	211.4	mJ	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 7)	PD	3.75	W
Thermal Resistance, Junction to Ambient (Note 7)	R _{0JA}	40	°C/W
Total Power Dissipation (Note 5)	PD	99	W
Thermal Resistance, Junction to Case (Note 5)	Rejc	1.51	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C

Notes:

5. Thermal resistance from junction to soldering point (on the exposed drain pad).6. Guaranteed by design. Not subject to product testing.7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



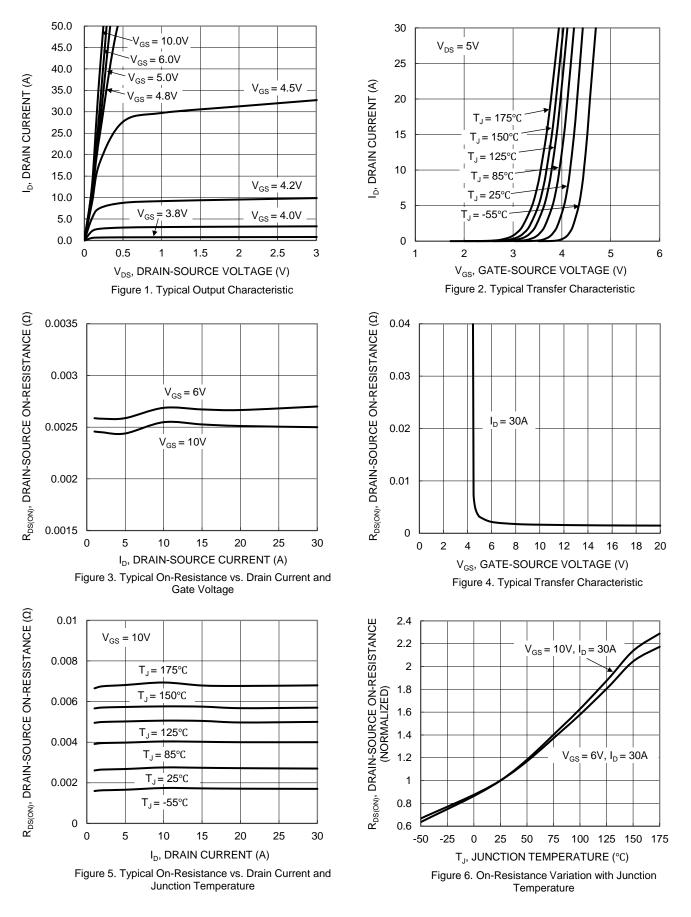
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)						-	
Drain-Source Breakdown Voltage	BV _{DSS}	80		_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS		_	1	μA	V _{DS} = 64V, V _{GS} = 0V	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	VGS(TH)	2	—	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Deserver	_	2.5	3.9	0	$V_{GS} = 10V, I_D = 30A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	2.7	6	mΩ	$V_{GS} = 6V, I_D = 30A$	
Diode Forward Voltage	Vsd	_	0.8	1.3	V	V _{GS} = 0V, I _S = 30A	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	Ciss		9081	_		$V_{DS} = 40V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss		556	_	pF		
Reverse Transfer Capacitance	Crss	_	80	_			
Gate Resistance	Rg		0.8	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	136	_		V _{DS} = 40V, I _D = 30A, V _{GS} = 10V	
Gate-Source Charge	Qgs	_	41	_	nC		
Gate-Drain Charge	Q _{gd}	_	32	_			
Turn-On Delay Time	t _{D(ON)}	_	19	_		$V_{DD} = 40V, V_{GS} = 10V$ $I_D = 30A, R_G = 2.5\Omega$	
Turn-On Rise Time	tR		31	_			
Turn-Off Delay Time	tD(OFF)	_	63	_	ns		
Turn-Off Fall Time	tF		27	—			
Reverse-Recovery Time	t _{RR}		58	_	ns		
Reverse-Recovery Charge	Q _{RR}		114		nC IF = 30A, di/dt = 100A/µs		

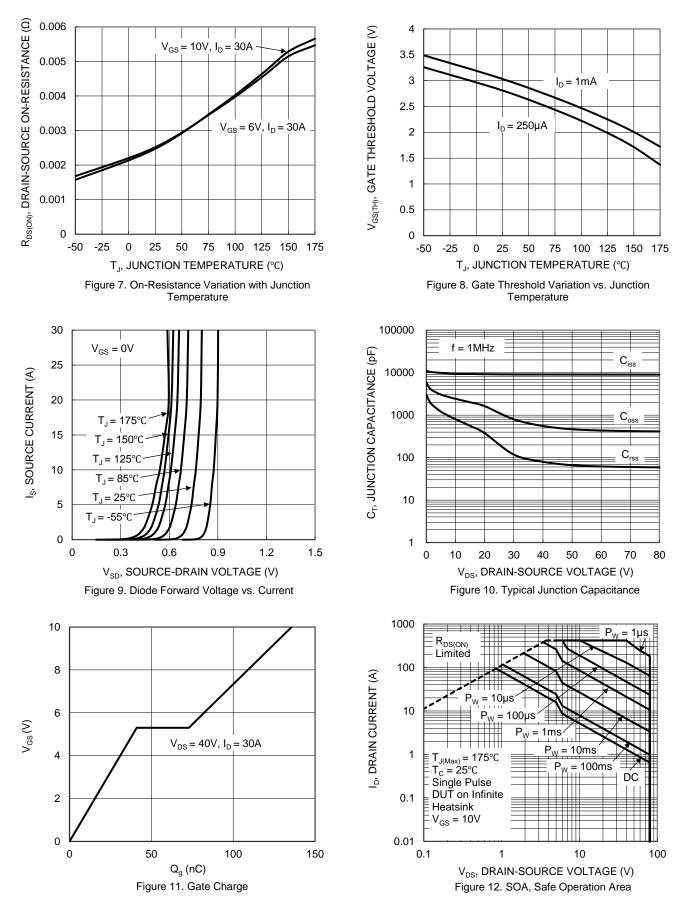
Note: 8. Short duration pulse test used to minimize self-heating effect.



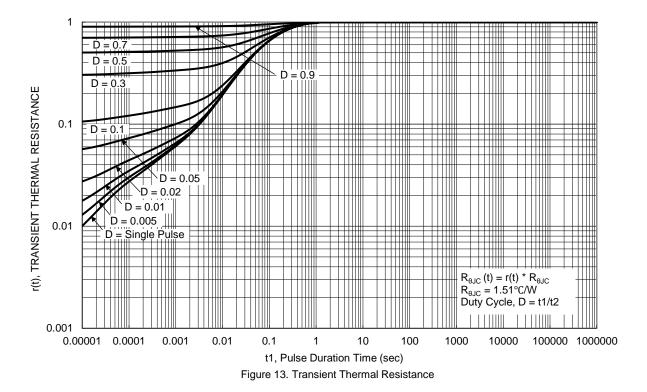
DMTH8003SPSW













PowerDI5060-8/SWP

(Type UX)

Max

1.10

0.05

0.50

0.35

0.230 0.330 0.277

5.15 BSC

5.10

3.96

4.18

6.40 BS

1.27BSC

0.835

0.835

0.225

4.005

12°

8°

5.60 6.00

3.46 3.86

4.195 4.595

0.200 0.400

All Dimensions in mm

0.25RE

Тур

1.00

0.41

0.25

4.90

3.76

3.98

5.80

3.66

4.395

0.735

0.735

0.300

0.125

3.605

<u>11°</u>

7°

Min

0.90

0

0.30

0.20

4.70

3.56

3.78

1.05

0.635

0.635

0.025

3.205

10°

6°

Α A1

b

b2

b4

С

D

D1

D2

Ε

E1

E2

E2a

е

k

L

La

L1

L4

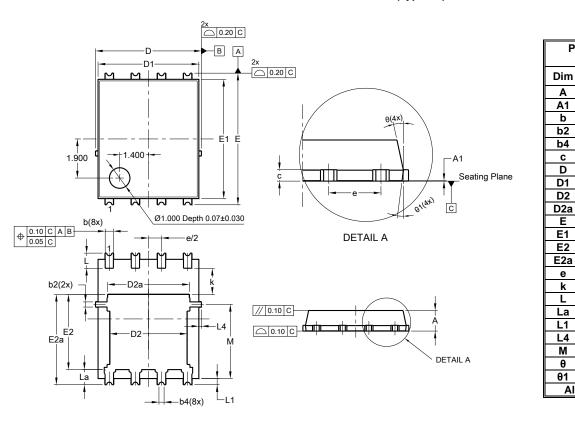
М

θ

θ1

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

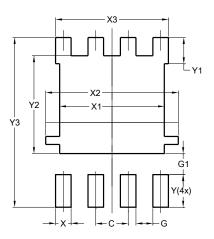


PowerDI5060-8/SWP (Type UX)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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